

W005M thru W10M

1.0 A Single-Phase Silicon Bridge Rectifier

Rectifier Reverse Voltage 50 to 1000V



Features

- This series is UL listed under the Recognized Component Index, file number E142814
- The plastic material used carries Underwriters Laboratory flammability recognition 94V-0
- Ideal for printed circuit board mounting
- High surge current capability
- High temperature soldering guaranteed 265 C /10 seconds at 5 lbs (2.3kg) tension

Mechanical Data

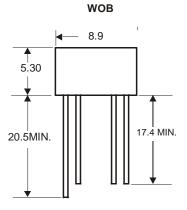
Case: Reliable low cost construction utilizing

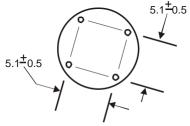
molded plastic technique

Terminals: Plated leads solderable per MIL-STD-202,

Method 208

Mounting Position: Any Weight: 0.05 ounce, 1.3 grams (approx)





Dimensions in millimeters(1mm =0.0394")

Maximum Ratings & Thermal Characteristics

Rating at 25 °C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz. For Capacitive load derate current by 20%.

Parameter	Symbol	W005M	W01M	W02M	W04M	W06M	W80W	W10M	unit
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified output current at TA=25 °C	IF(AV)	1.0							А
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	IFSM	60							А
Rating for fusing (t<8.3ms)	l²t	15							A ² sec
Typical thermal resistance per element (1)	RthJA	50.0							°C / W
Typical junction capacitance per element (2)	Cj	30							рF
Operating junction and storage temperature range	TJ, TSTG	-55 to + 150							°C

Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified. Resistive or Inductive load, 60Hz. For Canacitive load denate by 20 %

To Capacitive load defate by 20 70.										
Parameter	Symbol	W005M	W01M	W02M	W04M	W06M	W08M	W10M	Unit	
Maximum instantaneous forward voltage drop per leg at 2.0A	VF				1.1				V	
Maximum DC reverse current at rated TA =25 C DC blocking voltage per element TA =100 C		10 1000							μA	

Notes: (1)Thermal resistance from Junction to Ambemt on P.C.board mounting.

(2) Measured at 2.0 MHz and applied reverse voltage of 4.0 volts.

Rating and Characteristic Curves (TA\geq 25 C Unless otherwise noted) W005M thru W10M

Fig. 1 Derating Curve for Output Rectified Current

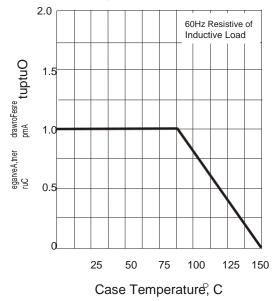


Fig. 3 Typical Instantaneous Forward Characteristics

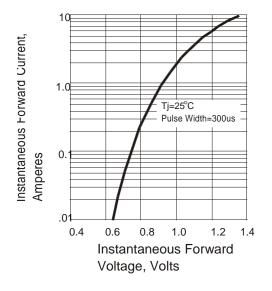


Fig. 2 Maximum Non-repetitive Peak Forward Surge Current

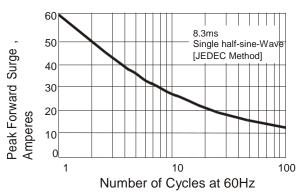


Fig. 4 Typical Reverse Characteristics

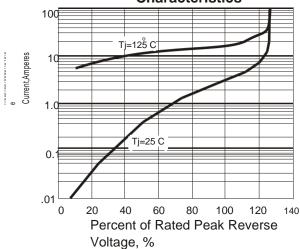


Fig. 5 Typical Junction Capacitance

